



PBSS4260QAZ Information



For Reference Only

Part Number PBSS4260QAZ
Manufacturer Nexperia USA Inc.

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 60V 2A DFN1010D-3

Package 3-XDFN Exposed Pad

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









PBSS4260QAZ Specifications

Manufacturer Part Number	PBSS4260QAZ
Manufacturer	Nexperia USA Inc.
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	3-XDFN Exposed Pad
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	2A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	190mV @ 50mA, 1A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	40 @ 2A, 2V
Power - Max	325mW
Frequency - Transition	180MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	3-XDFN Exposed Pad
Supplier Device Package	DFN1010D-3
	Report errors?

PBSS4260QAZ Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

PBSS4260QAZ Payment Methods





















PBSS4260QAZ Shipping Methods













If you have any question about PBSS4260QAZ, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com